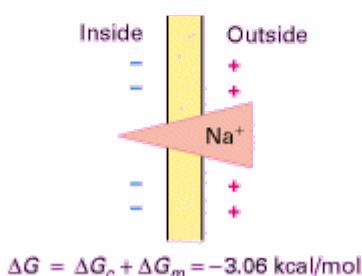
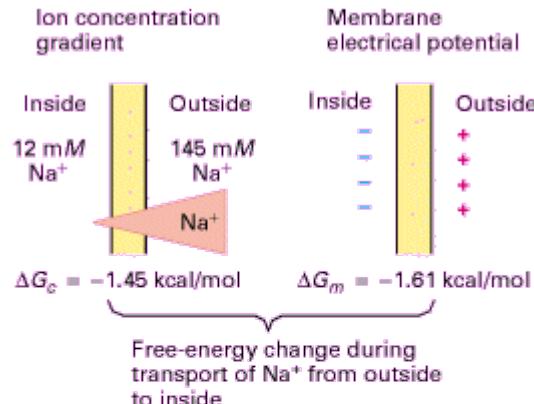


# Origin of the resting membrane potential



**Nernst-equation:**

relationship between potential difference and ion concentration in equilibrium for one sort of ion

$$E = V_{IC} - V_{EC} = \frac{RT}{zF} \ln \frac{[C]_{EC}}{[C]_{IC}}$$

**Goldman-Hodgkin-Katz-equation (GHK):**

resting membrane potential as a function of the ion concentrations and permeabilities

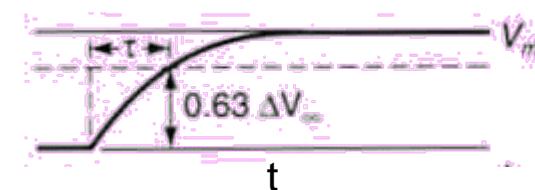
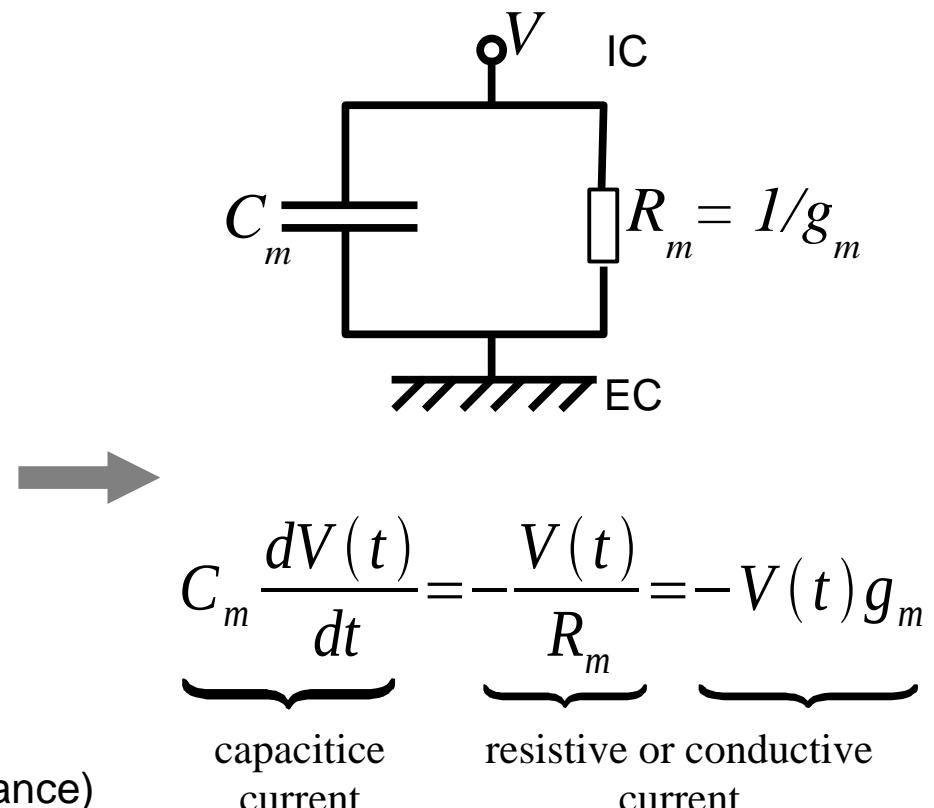
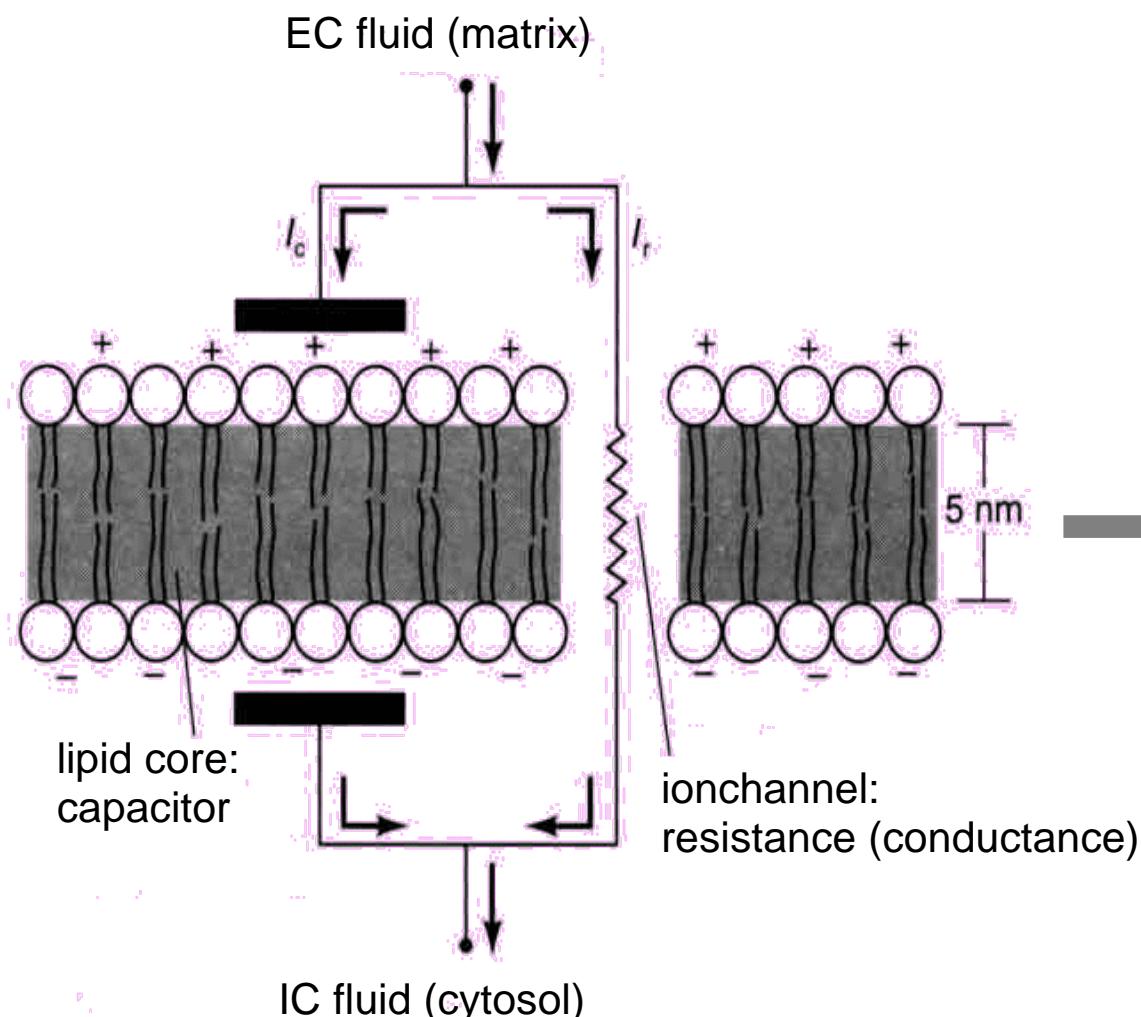
- more, independently moving ions
- constant electric force intensity through the membrane

$$V_{rest} = \frac{RT}{F} \ln \frac{P_K [K^+]_{EC} + P_{Na} [Na^+]_{EC} + P_{Cl} [Cl^-]_{IC}}{P_K [K^+]_{IC} + P_{Na} [Na^+]_{IC} + P_{Cl} [Cl^-]_{EC}}$$

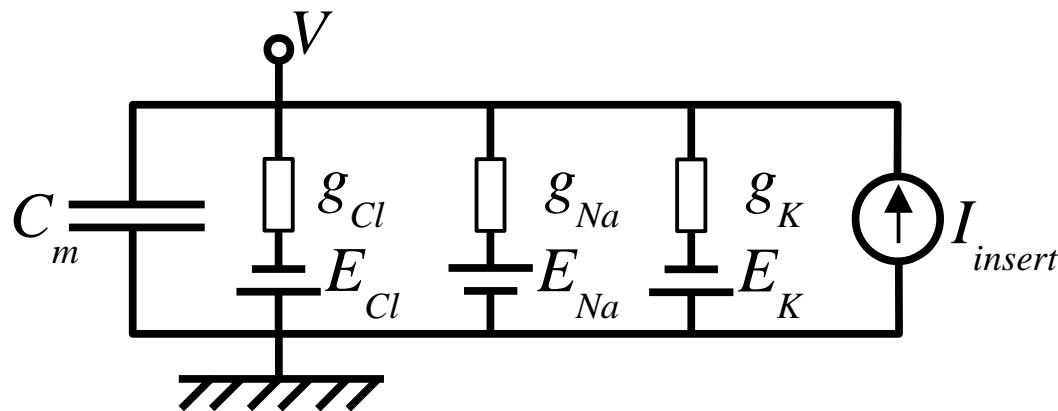
**Nernst-Planck equation:**

ionic flux (current) as a function of the electrochemical potentials

# Basics of the conductance-based models



# Model with parallel conductances



Equation for current equilibrium:

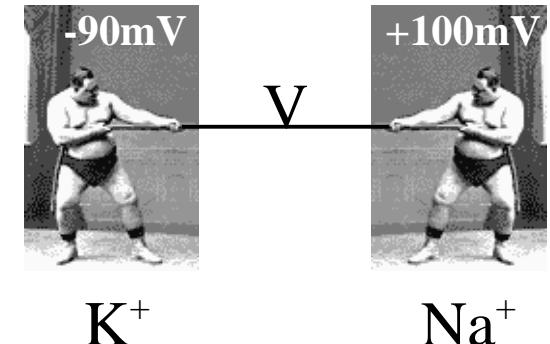
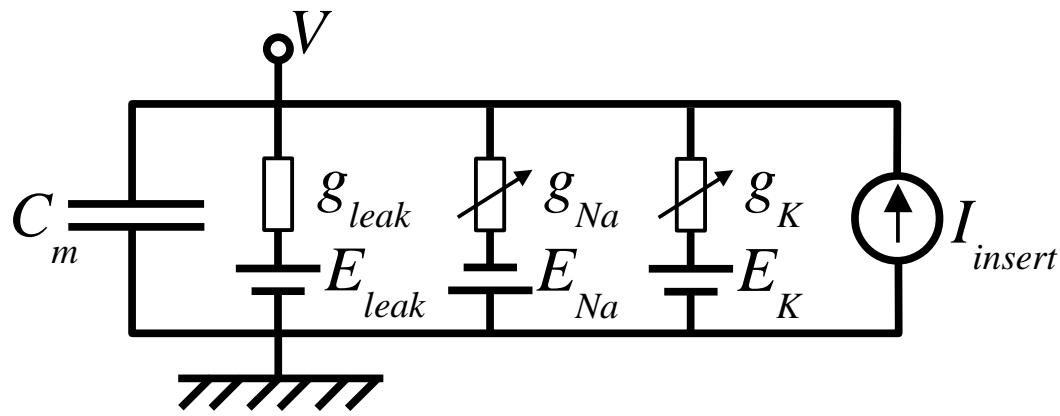
$$C_m \frac{dV(t)}{dt} = g_{Cl}(E_{Cl} - V(t)) + g_{Na}(E_{Na} - V(t)) + g_K(E_K - V(t)) + I_{insert}(t)$$

Nernst-  
potential

driving force

single ion current

# The Hodgkin-Huxley model / 1



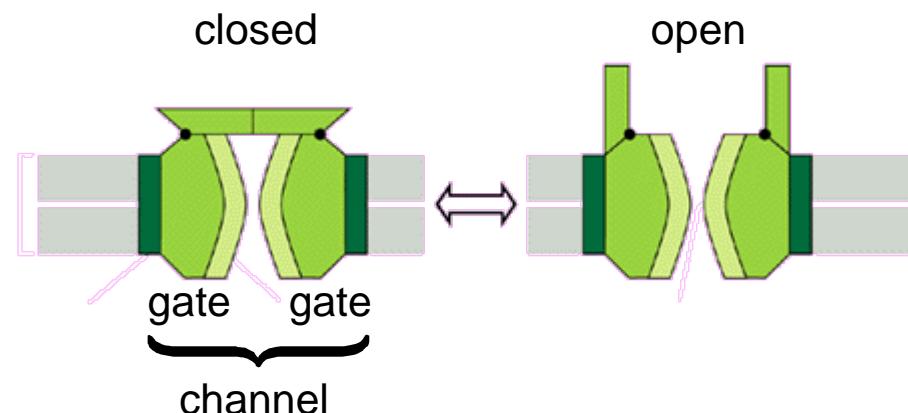
Equation for current equilibrium:

$$C_m \frac{dV(t)}{dt} = \underbrace{g_{leak}(E_{leak} - V(t)) + g_{Na}(t)(E_{Na} - V(t)) + g_K(t)(E_K - V(t))}_{\text{Leak current (mainly Cl}^-)} + I_{insert}(t)$$

Equations for ionic currents:

$$g_{Na}(t) = \bar{g}_{Na} \cdot m^3(t) \cdot h(t)$$

$$g_K(t) = \bar{g}_K \cdot n^4(t)$$



# The Hodgkin-Huxley model / 2

What is most important in the HH model: voltage dependent gating kinetics

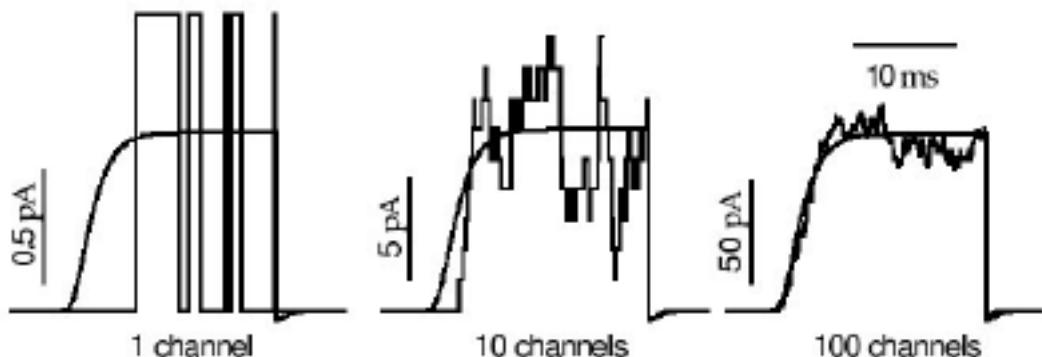
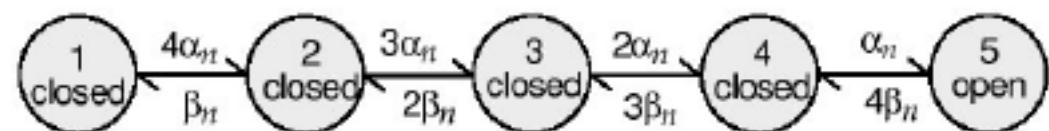
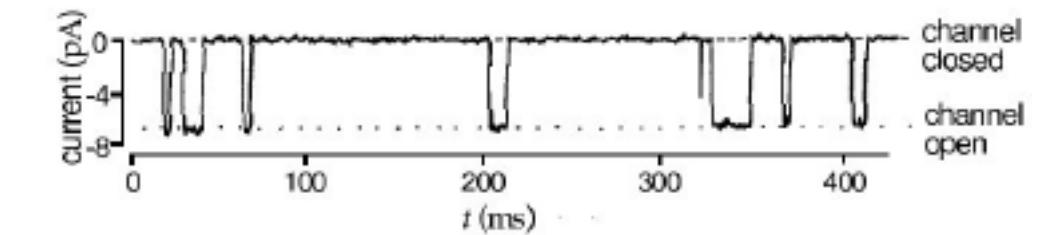
$$\text{closed} \xrightleftharpoons[\beta_m]{\alpha_m} \text{open}$$

$$1-m \quad m$$

$$\frac{dm(t)}{dt} = \alpha_m(V(t)) (1-m(t)) - \beta_m(V(t))m(t) = \frac{m_\infty(V(t)) - m(t)}{\tau_m(V(t))}$$

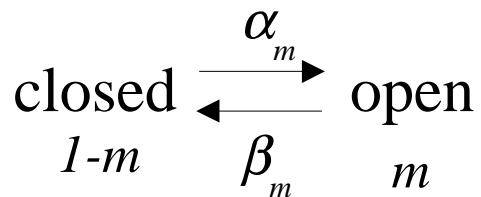
$$m_\infty(V) = \frac{\alpha_m(V)}{\alpha_m(V) + \beta_m(V)}$$

$$\tau_m(V) = \frac{1}{\alpha_m(V) + \beta_m(V)}$$



# The Hodgkin-Huxley model / 3

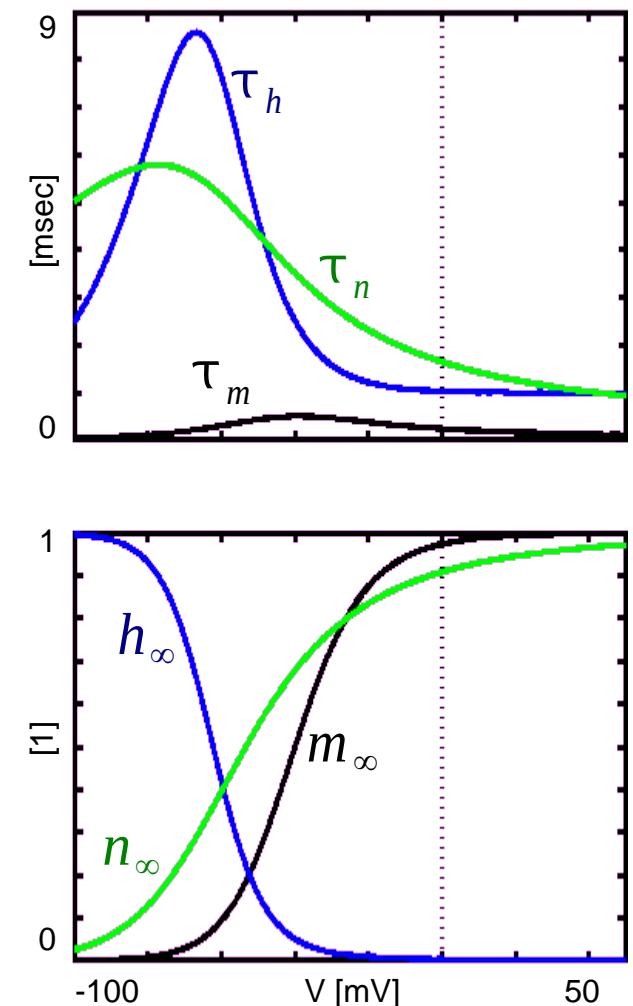
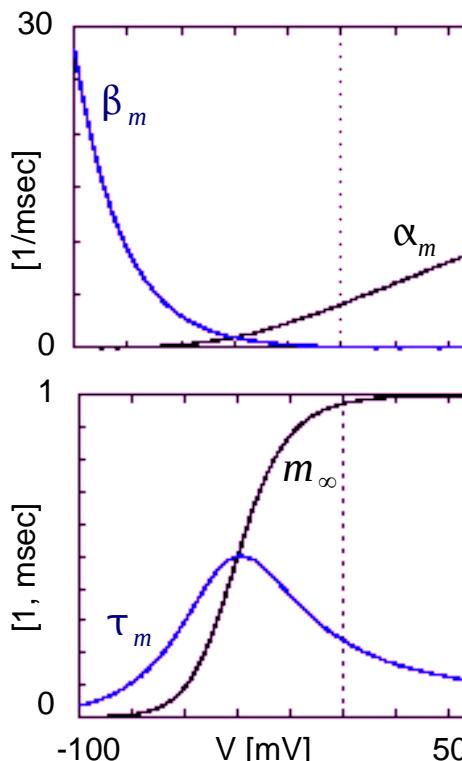
What is most important in the HH model: voltage dependent gating kinetics



$$\frac{dm(t)}{dt} = \alpha_m(V(t))(1-m(t)) - \beta_m(V(t))m(t) = \frac{m_\infty(V(t)) - m(t)}{\tau_m(V(t))}$$

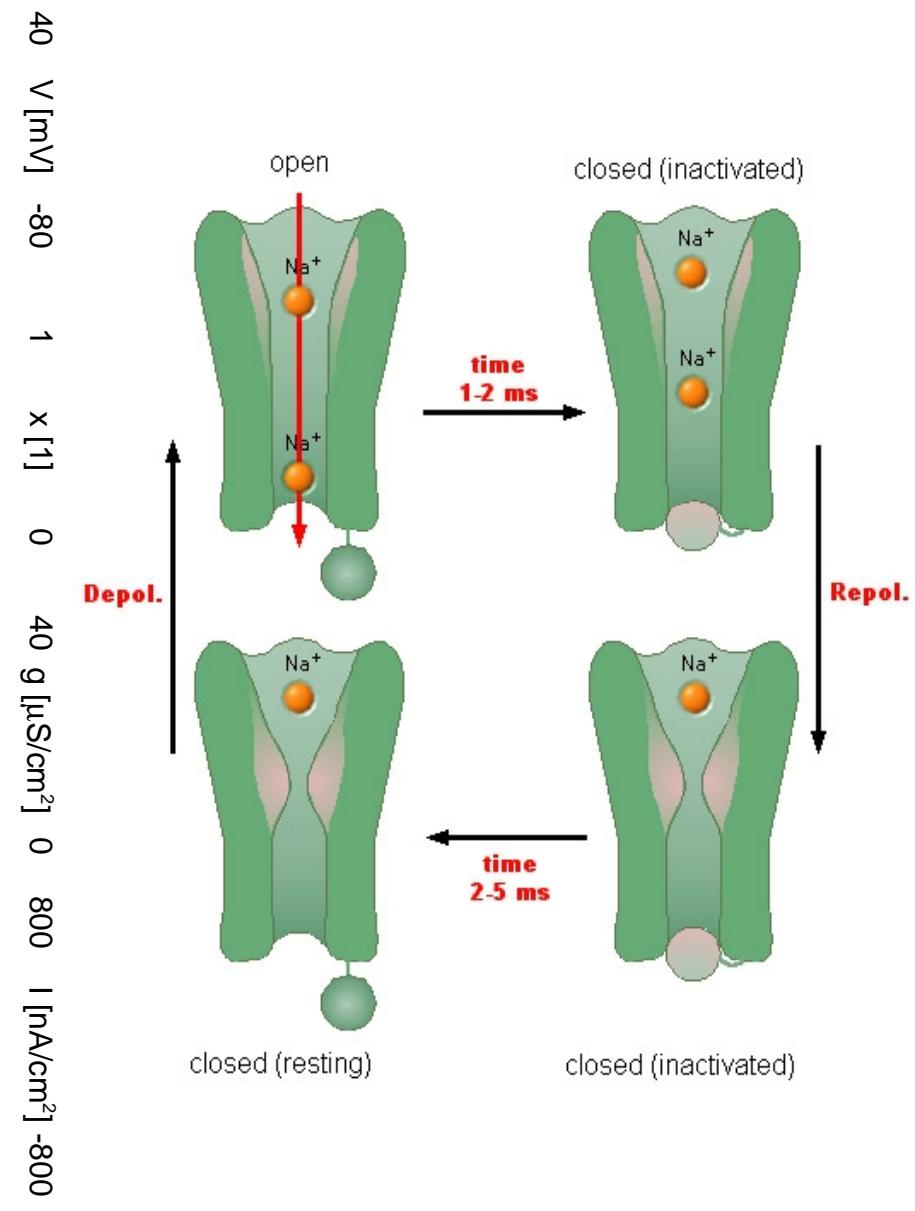
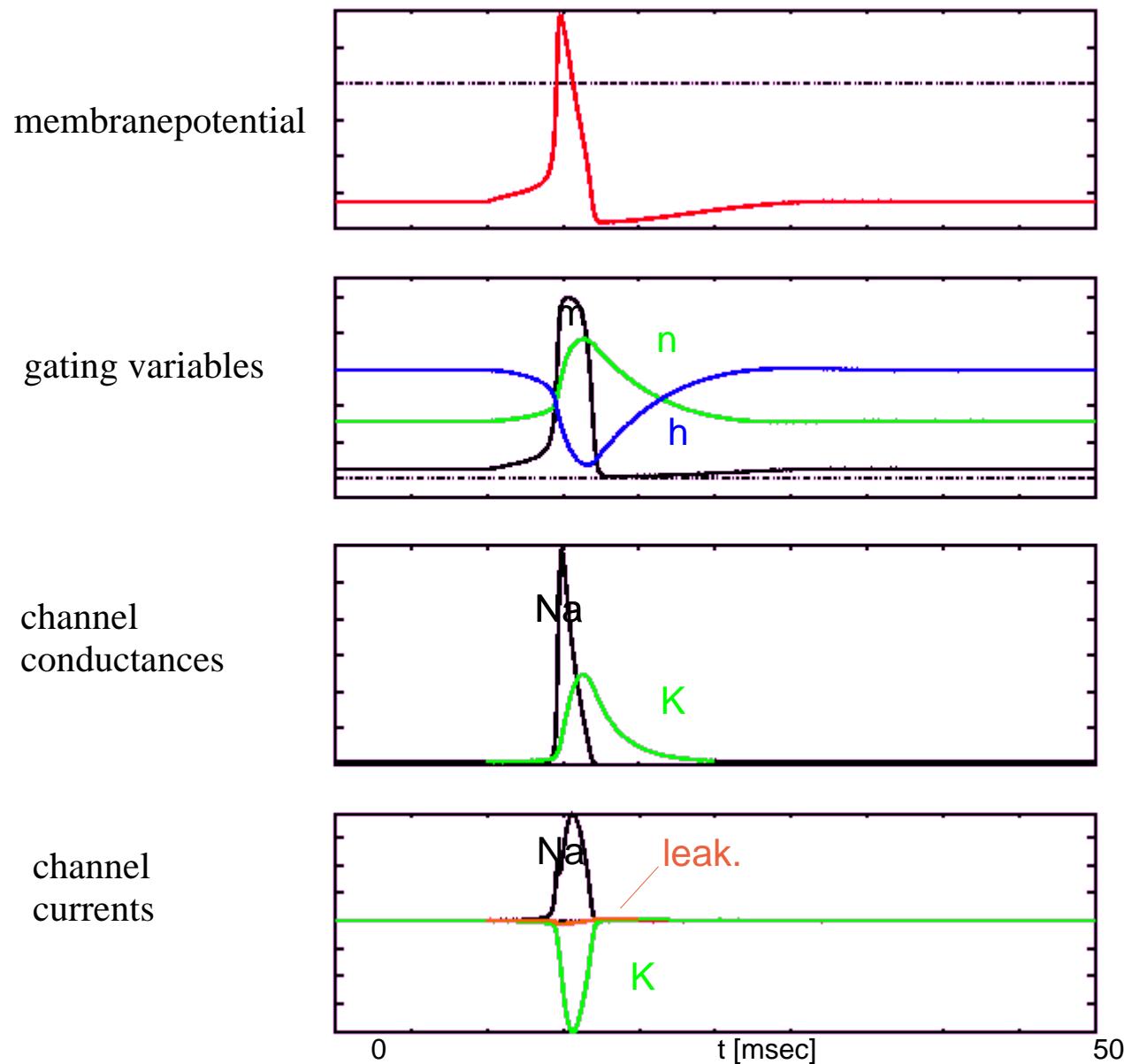
$$m_\infty(V) = \frac{\alpha_m(V)}{\alpha_m(V) + \beta_m(V)}$$

$$\tau_m(V) = \frac{1}{\alpha_m(V) + \beta_m(V)}$$

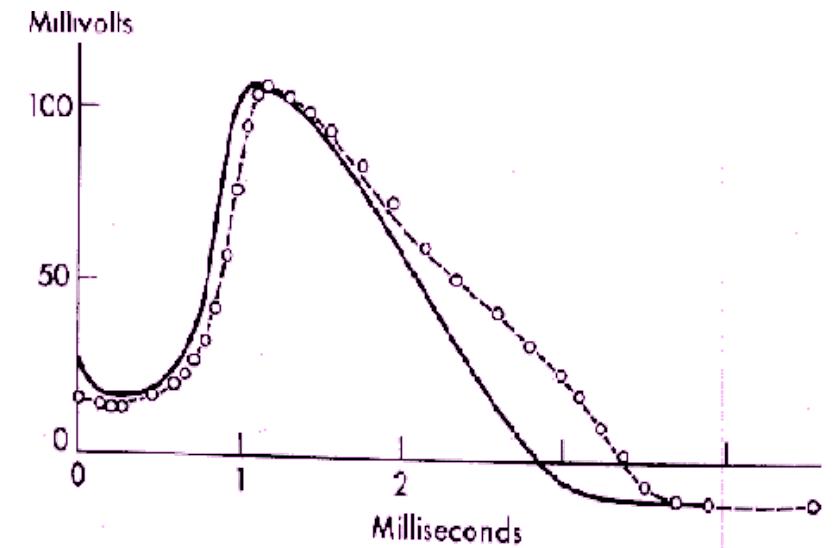


# The Hodgkin-Huxley model / 4

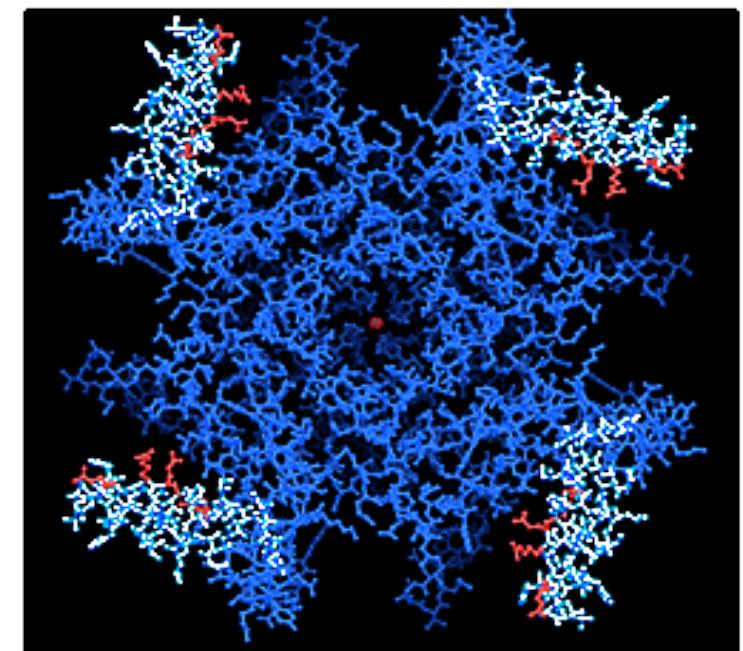
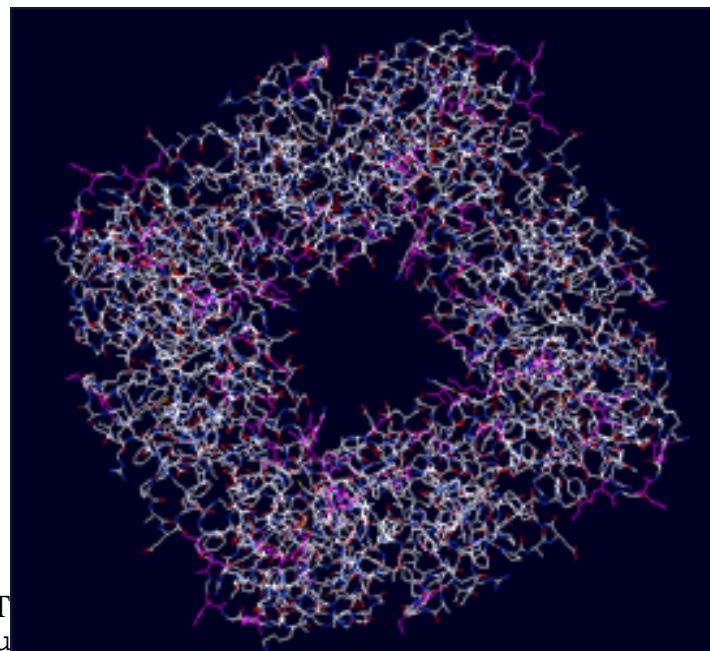
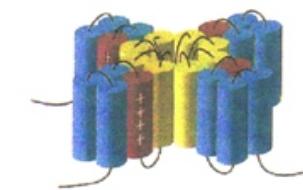
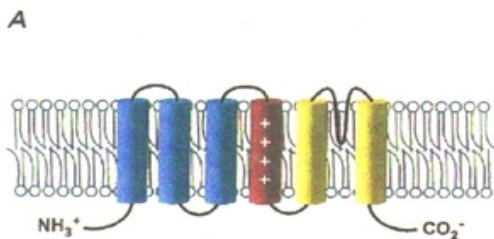
HH model in work:



# The Hodgkin-Huxley model / 5

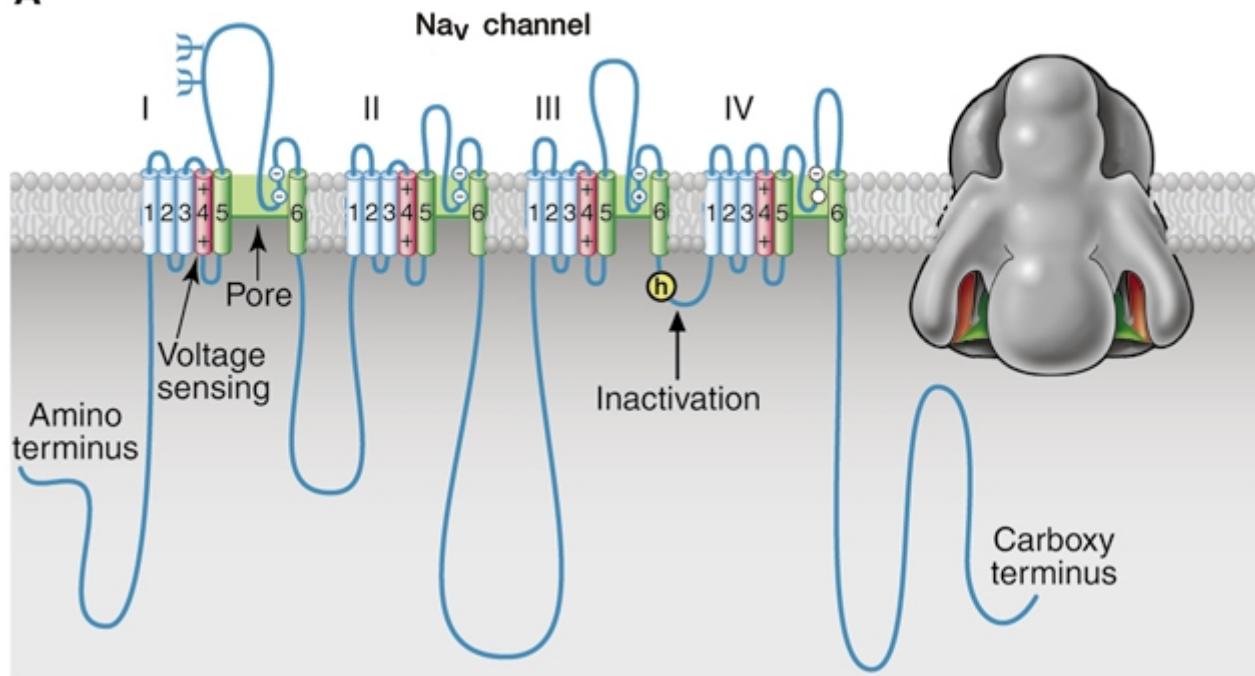


Sir John Carew Eccles, Alan Lloyd Hodgkin, Andrew Fielding Huxley: Awarded by Nobel-prize in medicine, 1963.



# The Hodgkin-Huxley model / 6

A



B

